



2SC3356-T1B-R25-A Information

Heisener.com

Part Number 2SC3356-T1B-R25-A

Manufacturer CEL

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - RF

Description SAME AS NE85633 NPN SILICON AMPL

Package TO-236-3, SC-59, SOT-23-3

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2SC3356-T1B-R25-A Specifications

Manufacturer Part Number	2SC3356-T1B-R25-A
Manufacturer	CEL
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	TO-236-3, SC-59, SOT-23-3
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	12V
Frequency - Transition	7GHz
Noise Figure (dB Typ @ f)	1.1dB @ 1GHz
Gain	11.5dB
Power - Max	200mW
DC Current Gain (hFE) (Min) @ Ic, Vce	50 @ 20mA, 10V
Current - Collector (Ic) (Max)	100mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-236-3, SC-59, SOT-23-3
Supplier Device Package	SOT-23-3
	Report errors?

2SC3356-T1B-R25-A Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2SC3356-T1B-R25-A Payment Methods

































If you have any question about 2SC3356-T1B-R25-A, please do not hesitate to contact us!

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